Synthesis, structure and ionic conductivity in nanopolycrystalline BaF₂/CaF₂ heterolayers[†]

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Atomistic simulations have shown that the calculated conductivity of nano-polycrystalline BaF_2/CaF_2 heterolayers is considerably higher than the component bulk materials and we predict that grain-boundary diffusion is the key to fast ionic conductivity in these systems.

Ionic conduction remains central to many solid-state reactions, fuel cell technologies, high temperature batteries and sensors.¹ Crucially, the microstructure of such systems has a profound influence on the properties.^{2,3} Experimental work by Sata *et al.* and Puin *et al.* on BaF₂/CaF₂ heterostructures² and nanocrystal-line CaF₂³ demonstrates that control over the fabrication of a particular microstructure can lead to an increase in the ionic conductivity. Here, we present an analogous approach to experiment: that of computer aided design, which can be used to (1) synthesise, (2) structurally characterise and (3) calculate the conductivity of the resulting system. The strategy provides a

 \dagger Electronic supplementary information (ESI) available: potential parameters and pertinent calculated physical properties for the perfect BaF_2 and CaF_2. See http://www.rsc.org/suppdata/cc/b3/b305393h/

framework for the computational design of materials with tailored ionic conductivities.

The computer aided design procedure is illustrated by synthesising models of nano-polycrystalline BaF_2/CaF_2 , characterising the structure using graphical techniques, calculating the conductivity and observing the trajectories of the fast conducting fluoride ions within the lattice.

Nano-polycrystalline BaF_2/CaF_2 heterointerfaces were synthesised using an amorphisation and recrystallisation strategy that we developed previously.⁴ Specifically, a block of BaF_2 (15 552 ions) was placed on top of a CaF_2 substrate (10 800 ions) using periodic boundary conditions to generate a layered structure. To amorphise the system, the BaF_2 was then compressed by 27%. Under molecular dynamical (MD) simulation (performed at 1200 K for 2.5 ps) the considerable compressive strain results in the amorphisation of first the BaF_2 and then the underlying CaF_2 . The MD simulation was then continued at lower temperatures to recrystallise the system. Specifically, 75 ps at 1200 K; 1455 ps at 800 K; 795 ps at 400 K and finally 612 ps at 0 K, the latter acting as an energy minimisation. The strategy is illustrated in Fig. 1.



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Fig. 1 Synthesis of nano-polycrystalline BaF_2/CaF_2 planar heterostructure. Top: schematics illustrating the BaF_2 and CaF_2 layers; starting configuration (left), compression induced amorphisation (middle) and final structure (right). Bottom: ion positions in the preparatory configuration (left) and amorphous configuration (middle). Barium is coloured blue; calcium is yellow and fluorine, red.



Fig. 2 Structural characterisation of the final configuration of the BaF_2/CaF_2 system. Top left a schematic illustrating the BaF_2 and CaF_2 layers; top right, a slice is cut through a BaF_2 slice to depict the nano-polycrystalline BaF_2 . Bottom right, the positions of individual ions within four intersecting grains are shown; a calculated trajectory for a fast moving fluoride ion (white) is superimposed and its pathway highlighted by the white arrows. Bottom middle, a section of one particular grain with polyhedral rendering and bottom left, ion positions of a unit cell.

All simulations were performed using the DL_POLY code⁵ using an NPT ensemble. The interatomic potentials, describing the interactions between the ions, are based upon the Born model of the ionic solid in which the ions interact *via* long-range Coulombic terms and short-range repulsive terms. Potential parameters and pertinent calculated physical properties for the perfect BaF₂ and CaF₂ using this potential model are available as ESI[†]. The activation energy for diffusion of fluoride ions in bulk BaF₂ and CaF₂, which is of prime importance in this study, is calculated to be 1.1 and 1.2 eV respectively and are within 10% of experimental values.

Graphical techniques were employed extensively to help understand and characterise the various microstructural features comprising the BaF_2/CaF_2 system. Images for the final structure are presented in Fig. 2.

Inspection of Fig. 2 reveals that the BaF₂ thin film comprises numerous misoriented nanocrystallites, about 2-10 nm in size, which are separated by grain-boundaries and grain junctions. The BaF₂ thin film also comprises about 5% Ca ions, which have migrated from the CaF₂ layers: inspection of the interfacial boundaries between the BaF2 and CaF2 crystallites reveal that there is a smooth transition from Ba to Ca concentrations perpendicular to the layers. Inspection of the nanocrystallites confirms that the BaF₂ has crystallised back into the fluorite structure. The atomistic structures of the grain-boundaries are similar to those observed experimentally (for example see ref. 6), which shows that the procedure is capable of generating realistic models of complex microstructures; the CaF2 films exhibit similar microstructures and nanocrystallite sizes to that of the BaF₂. We now calculate the ionic conductivity for the final (recrystallised) system and compare directly with available experimental data.

Atomic transport properties including the diffusion coefficients, activation energies and conductivities, can be extracted from the simulations using time dependent Mean Square displacements (MSD) and following standard approaches.⁷ To calculate the MSD's, MD simulations were run on the system for 300 ps at 500, 600, 800, 1000 and 1200 K. The calculated conductivities are presented in Fig. 3.

Inspection of Fig. 3 reveals that the calculated conductivity of the nano-polycrystalline BaF_2/CaF_2 model system is significantly higher compared with the component BaF_2 and CaF_2 materials. In addition, the activation energy associated with fluoride ion mobility in this system is calculated to be about 0.5 eV, which is less than half the value for the pure component materials.

Experimentally, Sata *et al.*, who fabricated nanometer scale crystalline BaF₂/CaF₂ planar heterostructures, using molecular beam epitaxy, observed that the conductivity was significantly



Fig. 3 Calculated conductivities (σ) for the nano-polycrystalline BaF₂/CaF₂ system. Experimental values for planar BaF₂/CaF₂ heterostructures,² nano-polycrystalline CaF₂³ and bulk BaF₂ and CaF₂² are included as a comparison.



Fig. 4 Ionic conductivity (S cm⁻¹) calculated as a function of depth (Å) through the BaF₂/CaF₂ system. The relative densities of ions comprising the system as a function of depth are depicted also to show the location of the various BaF₂ and CaF₂ layers. F-red; Ba-blue; Ca-orange and conductivity-black.

higher than the bulk materials. Remarkably, they found that the conductivity increased proportionally with interfacial density; the measured conductivities for 16 nm films, taken from the study of Sata *et al.*,² are included in Fig. 3. Similarly, Puin *et al.* measured ionic conductivity in nanocrystalline CaF₂ and concluded that the nanocrystalline CaF₂ shows a significantly higher overall conductivity than microcrystalline CaF₂; data, taken from the study of Puin *et al.*,³ are also included in Fig. 3. Our model system, which comprises periodic nano-polycrystalline BaF₂/CaF₂ layers, reflects microstructural attributes of both experimental systems.

One can also extract atomistic detail of the essential physics associated with ionic transport using our simulated models because the time-dependent atom positions are known explicitly. To illustrate this, Fig. 4 shows the conductivity (at 800 K) calculated as a function of depth through the BaF_2/CaF_2 system. Surprisingly, our calculations suggest a higher conductivity within the CaF_2 film compared with the BaF_2 . In addition, a further calculation was performed to establish the trajectories taken by fast moving fluoride ions. A representative trajectory pathway is superimposed onto Fig. 2. Inspection of this figure reveals that the fluoride ion traverses through grain-boundary regions within the CaF₂/BaF₂ system. Similarly, detailed analyses of other fluoride ion pathways reveal that the trajectories follow complex pathways along various CaF₂/CaF₂, CaF₂/BaF₂ and BaF₂/BaF₂ grain boundaries within the system with little impingement into bulk crystalline regions. As alluded to above, our calculations predict that the highest conductivity is within the CaF₂ layers — specifically, fluoride ions traversing through CaF₂/CaF₂ boundaries.

Our simulations help rationalise the experimental findings of Sata *et al.*² and Puin *et al.*³ Specifically, we propose that grainboundary diffusion facilitates the observed enhanced conductivity and epitomises the remarkable new structures and properties one can observe by traversing to the nanoscale.

The results presented here demonstrate that by modifying the computational synthetic procedure to fabricate a particular microstructure (this may also be modified to include, for example, different materials, layer thickness, nanocrystallite sizes, dislocations or other dopant species) and then calculating the conductivity, one can begin to identify the effect of microstructure on technologically important processes. Specifically, this study has illustrated that grain-boundary diffusion is the key to fast ionic conductivity in these nano-polycrystalline multilayered materials. Such insights assist in the design of new systems with promising applications where high conductivity is required at moderate temperatures such as fuel cells. Ultimately, the procedure can be exploited with an aim of predicting microstructures, which facilitate optimal conductivity. Accordingly, the strategy provides a framework for using the computational techniques to design systems with tailored ionic conductivities.

Notes and references

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